NSN 5961-01-196-4905

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-196-4905 **Inclosure Material:** Metal and glass **Overall Length:** 1.453 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 working peak reverse voltage and 96.0 repetitive peak reverse voltage and 80.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 70.00 amperes forward current, average and 600.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug **Specification Data:** 26916-019-005747 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No